

TOSHIBA MOS TYPE INTEGRATED CIRCUIT SILICON MONOLITHIC

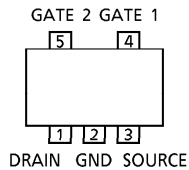
TA4006F

TV TUNER VHF RF AMPLIFIER APPLICATIONS.
TV TUNER UHF RF AMPLIFIER APPLICATIONS.
FM TUNER RF AMPLIFIER APPLICATIONS.

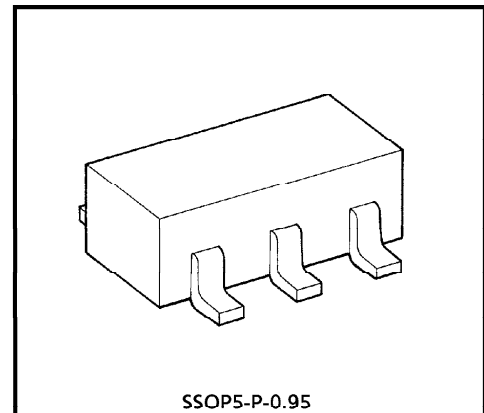
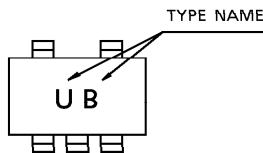
FEATURES

- On account of this Device Built-in Bias Circuit, Cut down number of articles.
- Low Noise Figure : NF = 2.0dB (Typ.)
- Operating Voltage : $V_{DD} = 6 \sim 11V$

PIN ASSIGNMENT (TOP VIEW)



MARKING



SSOP5-P-0.95
 Weight : 0.014g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{DD}	11	V
Gate 2-Source Voltage	V_{G2S}	± 8	V
Supply Current	I_{DD}	30	mA
Power Dissipation	P_D^*	250	mW
Operating Temperature	T_{opr}	- 40~85	°C
Storage Temperature	T_{stg}	- 55~125	°C

* When mounted on the glass epoxy board of 2.5cm² × 1.6t

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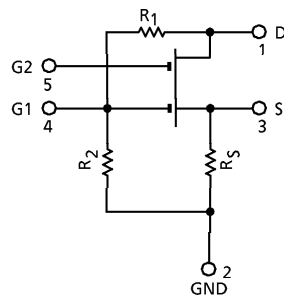
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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate 2 Leakage Current	I_{G2SS}	—	$V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6V$	—	—	± 50	nA
Gate 2-Source Cut-off Voltage	$V_{G2S(OFF)}$	—	$V_{DD} = 5V, I_{DD} = 150\mu A$	0.5	1.0	1.5	V
Supply Current	I_{DD}	—	$V_{DD} = 9V, V_{G2} = 7V$	6	—	14	mA
Input Capacitance	C_{iss}	—	$V_{DD} = 9V, V_{G2} = 7V$	1.5	2.2	2.9	pF
Output Capacitance	C_{oss}	—	$f = 1MHz$	0.8	1.4	2.0	pF
Power Gain	G_{ps}	1	$V_{DD} = 9V, V_{G2} = 7V$	19	24.0	—	dB
Noise Figure	NF	1	$f = 500MHz$	—	2.0	2.9	dB

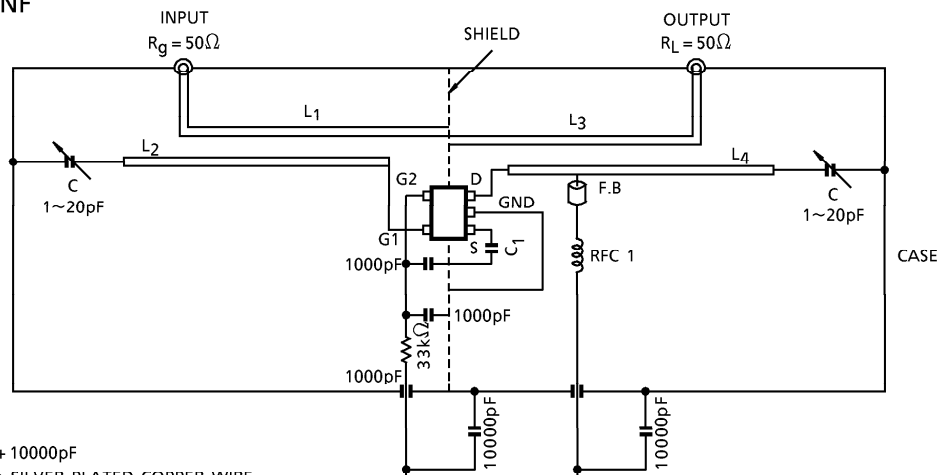
I_{DD} Classifications : Y : 6~10mA, GR : 8~12mA, BL : 10~14mA.

EQUIVALENT CIRCUIT

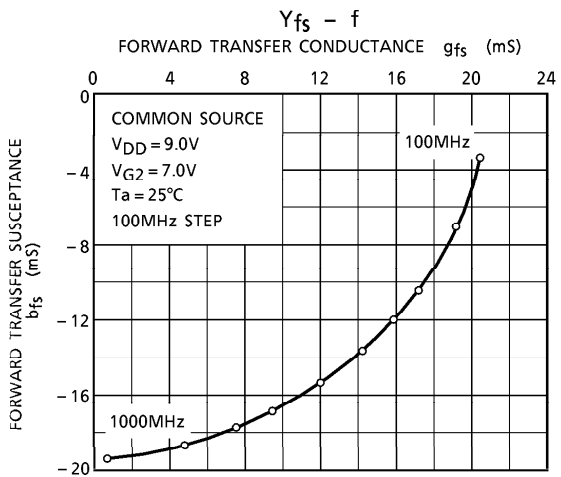
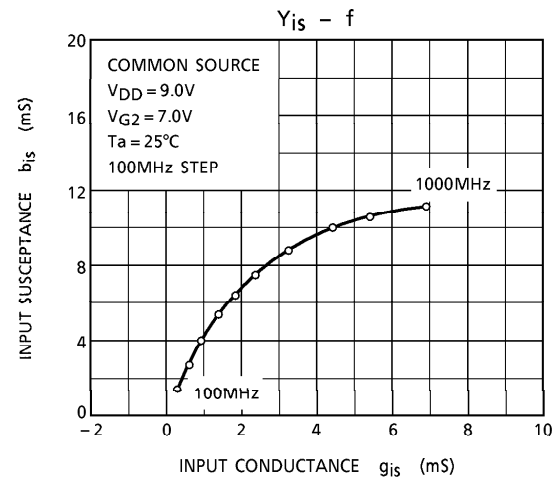
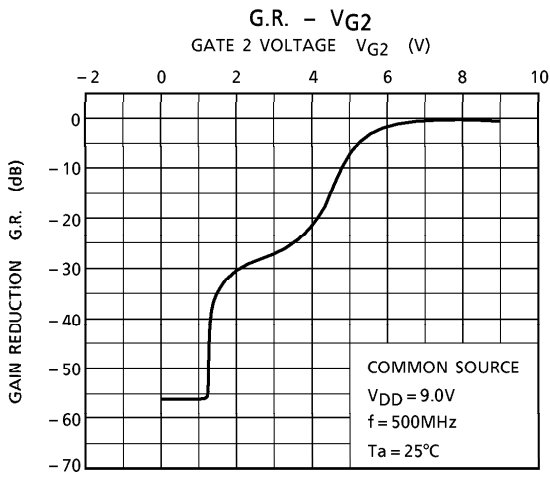
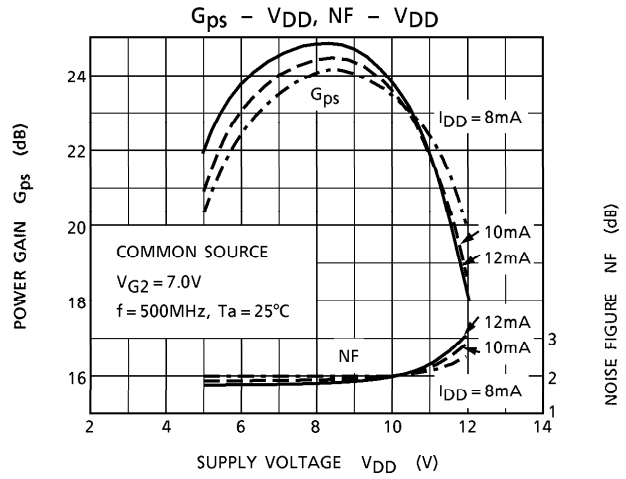
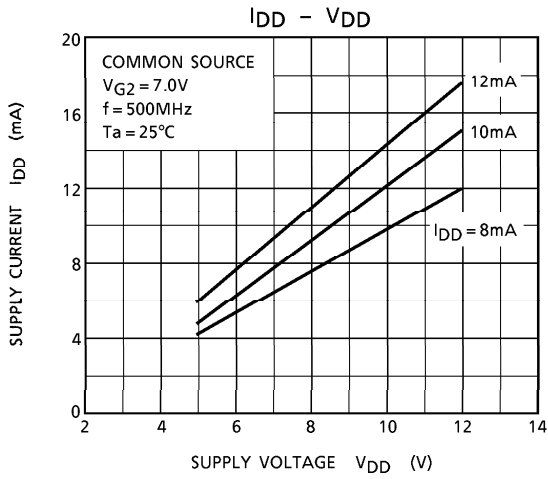


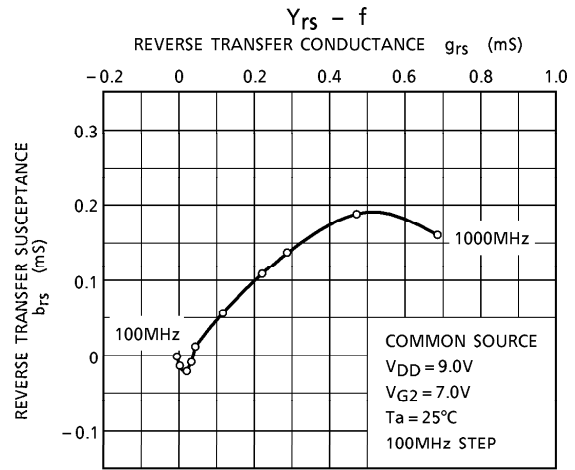
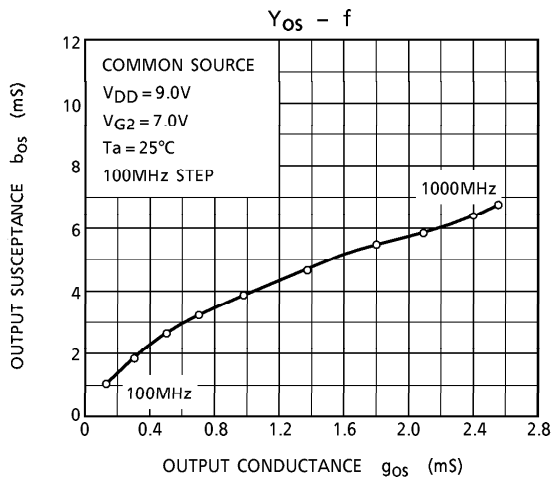
TEST CIRCUIT 1

500MHz, G_{ps} , NF



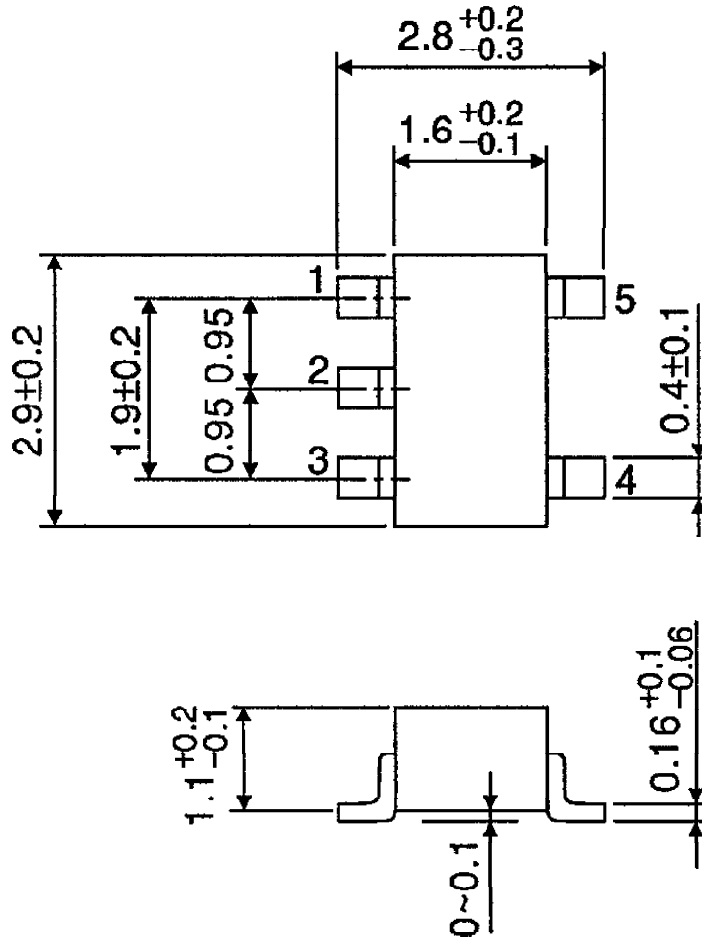
- C_1 : 1000pF + 10000pF
- L_1, L_4 : $\phi 0.8mm$ SILVER PLATED COPPER WIRE
- C : AIR TRIMMER TTA25A200A (MURATA MFG. Co., Ltd.)
- RFC 1 : $\phi 0.35mm$ COPPER WIRE 3mm ID, 10T





OUTLINE DRAWING
SSOP5-P-0.95

Unit : mm



Weight : 0.014g (Typ.)